

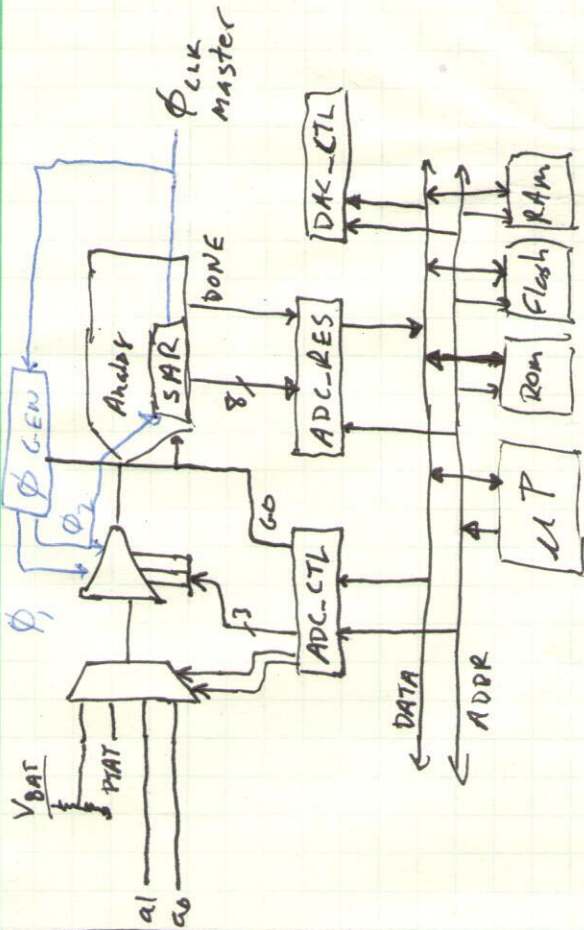
rf interface

timing

switch issues

forward biasing diodes

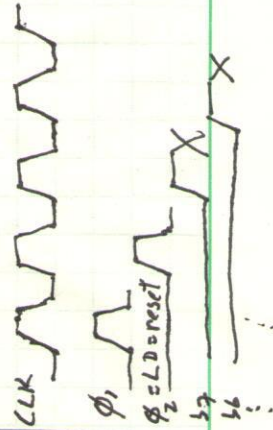
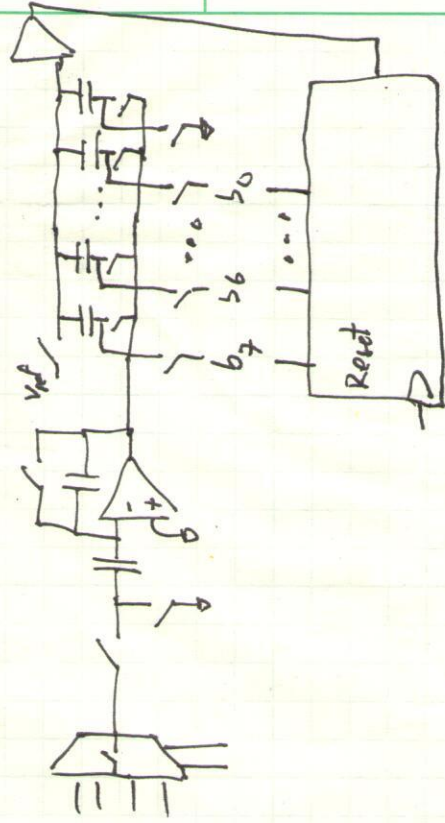
charge injection



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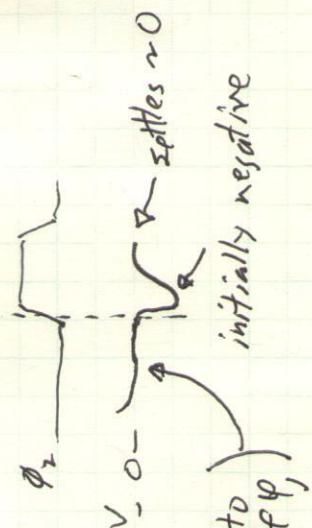
pseudo-C code
#define ADC_CTL 0x1000
#define ADC_RES 0x1004
#define DAC_CTL 0x1008
#define BATTERY 3
int gain = 4; // 1..8
MEX = BATTERY;
go = 1
*ADC_CTL = (gain-1) << 4 | MUX << 1 | go;
*ADC_CTL = *ADC_CTL & (~0x1); // reset go
for (i=0; i<100; i++) // wait 100 cycles of 10 mhz
    x = *ADC_RES;
    // times cycles loop
    // there are better ways to do this
    
```

timing



Issues w/ switches

- charge injection
- forward biased diodes



V_- settles close to ground by end of ϕ_1

initially negative

settles ~ 0

if there were no op-amp, when ϕ_2 goes high V_- would go to $-V_{in}$, e.g. $-0.8V$

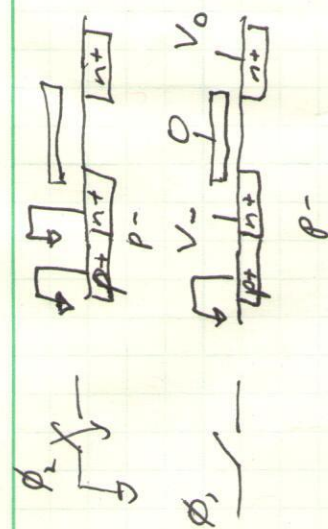


worse if $C_1 > C_2$ ($G=8$)

$\tau_{switch} = R_{on}(C_1 \text{ series } C_2)$ (slowest when $G=8$)

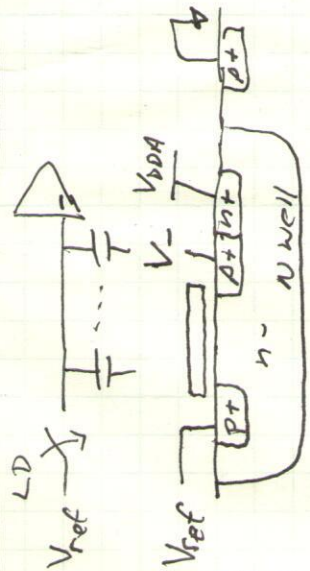
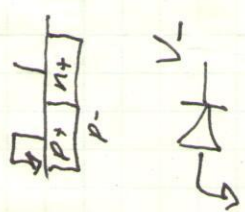
V_{in} is large

ϕ_2 has a fast edge



what if $V_- = -0.1V$?

$= -0.5V$?



$$V_- = V_{ref} - V_{in} + \frac{B}{2n} V_{ref}$$

if $V_{in} = 0$ and $B = 0.8$, $V_- \approx 2 V_{ref}$

never happens, but if $B = 0.8$

$$V_- \approx 1.5 V_{ref} = 1.2V$$

1.2V 0.8V



1.1



0.8